

Introduction

- Mesoscopic electron systems in quantum dots are known to reveal interesting correlation effects, e.g. Wigner crystallization [2]
- Extensions in present work: 1. Single-electron control of melting/ conductivity [1] confirmed by dynamic simulation. 2. Generalization to mesoscopic electron-hole *bilayers* (vertically coupled quantum dots): crystallization of excitons observed, energy spectrum is found.

Single-electron control of circular cur-2 rent in quantum dots

- Investigation of the response of mesoscopic 2D electron clusters to external angular excitation.
- Control of the angular current by addition/removal of a single electron \Rightarrow application to single-electron devices [1].
- Idea: use the striking difference of orientational melting temperatures of cluster with N = 19, 20, see Fig. 1, to switch between liquid-like ("conducting") and crystal-like ("insulating") behaviour [2].



Fig. 1 Left: Ground state configuration of N = 19 and N = 20 clusters. Right: Phase diagram of the "crystal" phases for N = 19, 20. The outer (inner) lines are the radial (angular) melting phase boundaries. The classical melting takes place at specific values of the coupling parameters: $\Gamma_{20}^{RM} = 83, \Gamma_{19}^{RM} = 154, \Gamma_{19}^{OM} = 330 \text{ and } \Gamma_{20}^{OM} = 3.4 \cdot 10^{11}. \ \Gamma = \left(\frac{e^2/\epsilon \langle a \rangle}{k_B T}\right).$

Model and simulation idea $\mathbf{2.1}$

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Hamiltonian of a single quantum dot:

$$\mathbf{r} = -\sum_{i=1}^{N} \frac{\hbar^2 \nabla_i^2}{2m_i} + \sum_{i=1}^{N} \frac{m_i \omega_0^2 r_i^2}{2} + \sum_{i$$

After reaching the ground state configuration (see above) the system is disturbed by: (1) angular external force, (2) friction. We calculate the response by solving:

$$m_{e}\dot{\vec{v}}_{i}(t) = \sum_{i,j}\vec{F}_{ij} + \vec{F}_{i}^{ext} - \gamma\vec{v}_{i}(t), \quad i = 1, \dots N$$

- External force, $\vec{F}_i^{ext} = const$, acts only on the outer shell.

- To prevent rotation of the cluster as whole we pinned one particle of the *inner shell*, it allows to move only radially.

- One particle is *slowly* added/removed to the inner shell.

Equilibrium and dynamical properties of few particle systems in single and coupled e-h-quantum dots

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<u>Result</u>: I) Angular current (intershell rotation) flows in N = 20 cluster and stops after removal of 20-th particle.



Fig. 2: Dependence of the outer shell current on time. Averaged current is also shown. Black line is the charge of the inserted particle. Time is in units of $T_0 = 2\pi/\omega_0$. Units of current is $I_0 = e \frac{r_0}{T_0}$, with unit of length $r_0 = \left(\frac{2e^2}{\epsilon m\omega_0^2}\right)^{1/3}$.

II) We demonstrate principial possibility of creation the device with open and close states. The inserted particle should be inserted about 30 T_0 , friction coefficient should be choosen to ensure steady constant current in open state.

Mesoscopic electron-hole bilayer sys-3 tems



Hamiltonian of two vertically coupled electron-hole QD's:

$$\hat{H} = H_e + H_h - \sum_{i=1}^{N_e} \sum_{j=1}^{N_h} \frac{e_i e_j}{\epsilon \sqrt{|\mathbf{r}_i - \mathbf{r}_j|^2 + d^2}},$$
$$\hat{H}_{e(h)} = \sum_{i=1}^{N_{e(h)}} \left[-\frac{\hbar^2}{2m_i} \nabla^2 + V_{e(h)}(\mathbf{r}_i) + \sum_{i$$

We consider symmetrical bilayers: $m_e = m_h = m$. Confinement potentials are equal: $V_e = V_h = \frac{1}{2}m\omega^2 r^2$.

The state of the system is governed by two competing effects:

- Intra-layer Coulomb repulsion of particles \rightarrow "crystallization" in each layer
- Inter-layer attraction between electrons and holes \rightarrow formation of interwell excitons (or dipoles in the classical limit)

Classical mesoscopic bilayers $\mathbf{3.1}$



exact dependence, $\left(\frac{U_{corr}}{N} + \frac{e^2}{d}\right)/U$

ndependent layers, $U_{C} \sim \frac{e^2}{2}$

d/a(d)

dipol limit, $U_{D} \sim \frac{e^2 d^2}{2^3}$

2.5 5 7.5 10 12.5 15 17.5 20

0.6

0.4

0.2

Fig. 4 Intra-layer particle distance, a(d), in the ground state as a function of layer separation d (the unit of length is a_c). We have two limits: (I) $d \ll 1$, a(d) is determined only by dipole-dipole interaction (mean interparticle distance a_D),

(II) $d \gg 1$, intra-layer Coulomb interaction dominates (mean distance a_C). Note the different power laws of a(d) in the two limits

Fig. 5 Correlation energy (binding energy of excitons is excluded) for different distances between layers, d. Figure compares the exact correlation energy with the two limits: system of dipoles, U_D , and independent layers, U_C .

crystal to exciton liquid (excitons are preserved).



Fig. 6, 7 Excitation spectrum of normal modes for three and eight excitons as a function of distance d. The eigenfrequencies, ω , are in units of the trap frequency divided by $\sqrt{2}$. There are always 2N normal modes. Insets display the eigenvectors and eigenvalues for d/a = 1.3 (in descending order) computed from the Hesse-Matrix:

 $H_{ij} = \partial^2 H / \partial r_i \partial r_j,$ $ec{r}=\{x_1,y_1,\ldots x_N,y_N\}$ is a vector of all particle coordinates.

For all systems one always finds three trivial, universal modes: A) rotation of the whole system, $\omega^2 = 0$, B) vibration of the center of mass, $\omega^2 = 2$ (two-fold degenerate),

C) breathing mode, exact result for general interaction of the form $U \sim \frac{e^2}{a^{1+p}}$.

$$\omega_{br}^2 = 2m(3+p) = \begin{cases} 6, \quad p = 0 \quad \text{Coulomb} \\ 10, \quad p = 2 \quad \text{dipole} \\ 14, \quad p = 4 \quad \text{quadrupole} \end{cases}$$

For excitons $\omega_{hr}^2 = 20$ (dipole interaction, $m = m_e + m_h$).

<u>Result:</u> Analysis of mode spectrum reveals:

I) d > 1: anti-phase rotation of shells in the electron and hole layers has the lowest energy [mode 11 (Fig. 6) and 31 (Fig. 7)] \Rightarrow with increasing temperature/density the two layers become decoupled and excitons are destroyed. II) d < 1: lowest excitation energies are related to pairwise coupled motion of electrons and holes \Rightarrow crystal melting proceeds via transition from exciton





crystal: $T \leq 1/7 \times 10^{-3}$ Ha, $r_s \gtrsim 20$. Examples: a) **GaAs** -based structures: $T \leq 40 \, mK$ and $\rho \leq 8 \times 10^8 \, cm^{-2}$ b)**CdTe** -based structures: $T \leq 100 \, mK$ and $\rho \leq 9 \times 10^9 \, cm^{-2}$ c) **ZnSe** -based structures: $T \leq 400 \, mK$ and $\rho \leq 3 \times 10^9 \, cm^{-2}$

3. Highest melting temperature is observed for intermediate $d \sim 25 a_B$.



Summary and Outlook

scenario clarified.

References

Results for temperature and density boundaries for the existence of e-h

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3.3 Phase diagramm of e-h bilayers
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1. Exciton crystal can exist only for inter-layer distances $d \gtrsim 5a_B$ and critical density parameter $r_s \gtrsim 20$.

2. Interlayer attraction leads to stabilization of crystal phase: e.g., for exciton cluster, $N_e = N_h = 8$, coupling parameter r_s changes from $r_s \approx 56 \text{ (for } d \to \infty) \text{ to } r_s \approx 20 \text{ (at } d = 5a_B).$

 \Rightarrow Single-electron control of melting/conductivity is demonstrated. \Rightarrow Evidence for crystallization of excitons is found (not possible in single) layers or for $d \leq 5a_B$).

 \Rightarrow Two crystal phases exist: exciton and decoupled e/h crystals.

 \Rightarrow Phase diagram (in T, n, d space) of mesoscopic e-h systems is presented. \Rightarrow (Classical) Excitation spectrum has been found and crystal melting

 \Rightarrow Bose condensation of mesoscopic excitons expected at higher densities.

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